

**8-UNIT 400mA DARLINGTON TRANSISTOR ARRAY WITH CLAMP DIODE****DESCRIPTION**

The M54522P, 8-channel sink driver, consists of 16 NPN transistors connected to form eight high current gain driver pairs.

**FEATURES**

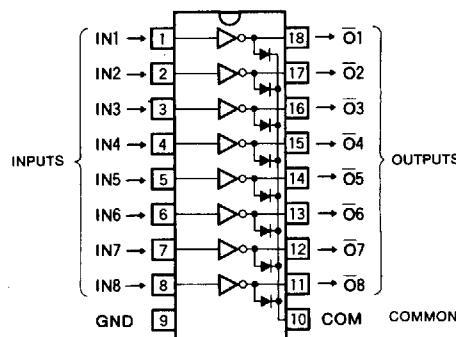
- High output sustaining voltage to 40V
- High output sink current to 400mA
- Integral diodes for transient suppression
- PMOS Compatible input
- Wide operating temperature range ( $T_a = -20 \sim +75^\circ\text{C}$ )

**APPLICATION**

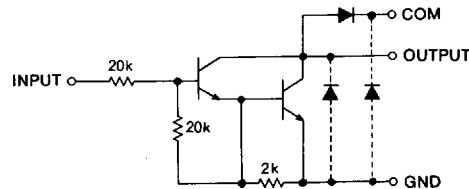
Relay and printer driver, LED or incandescent display digit driver, Interfacing between MOS/BIPOLAR logics and high power loads

**FUNCTION**

The M54522P is comprised of eight NPN darlington driver pairs with  $20\text{k}\Omega$  series input resistors. Each output has an integral diode for inductive load transient suppression. The cathodes of the diodes are connected together to pin 10. All emitters and the substrate are connected to pin 9. The outputs are capable of sinking 400mA and will withstand 40V in the OFF state.

**PIN CONFIGURATION (TOP VIEW)**

Outline 18P4

**CIRCUIT SCHEMATIC**

The diodes shown by broken line are  
parasite diodes and must not be used

Unit : Ω

**ABSOLUTE MAXIMUM RATINGS** ( $T_a = -20 \sim +75^\circ\text{C}$ , unless otherwise noted)

Symbol	Parameter	Conditions	Ratings	Unit
$V_{CEO}$	Output sustaining voltage	Transistor OFF	-0.5 ~ +40	V
$I_C$	Collector current per channel	Transistor ON	400	mA
$V_I$	Input voltage		-0.5 ~ +40	V
$I_F$	Clamp diode forward current		400	mA
$V_R$	Clamp diode reverse voltage		-0.5 ~ +40	V
$P_d$	Power dissipation	$T_a = 25^\circ\text{C}$	1.79	W
$T_{opr}$	Operating temperature		-20 ~ +75	°C
$T_{stg}$	Storage temperature		-55 ~ +125	°C

MITSUBISHI (DGTL LOGIC)

**8-UNIT 400mA DARLINGTON TRANSISTOR ARRAY WITH CLAMP DIODE****RECOMMENDED OPERATIONAL CONDITIONS** ( $T_a = -20 \sim +75^\circ\text{C}$ , unless otherwise noted)

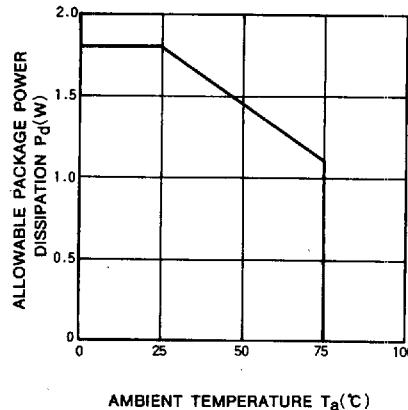
Symbol	Parameter	Limits			Unit
		Min	Typ	Max	
$V_O$	Output voltage	0		40	V
$I_C$	Collector current per channel	Percent duty cycle less than 7%	0	400	mA
		Percent duty cycle less than 30%	0	200	
$V_{IH}$	"H" Input voltage	$I_C=400\text{mA}$	8	30	V
		$I_C=200\text{mA}$	4	30	
$V_{IL}$	"L" Input voltage	$I_{OL\text{leak}}=50\mu\text{A}$	0	0.5	V

**ELECTRICAL CHARACTERISTICS** ( $T_a = -20 \sim +75^\circ\text{C}$ , unless otherwise noted)

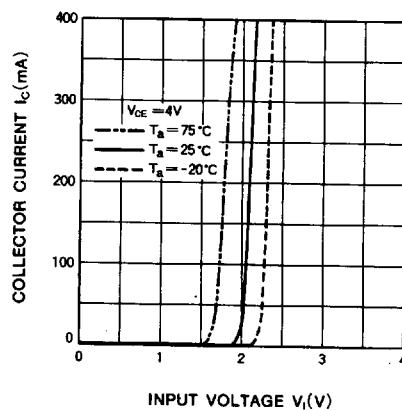
Symbol	Parameter	Test conditions	Limits			Unit	
			Min	Typ*	Max		
$V_{IBR CEO}$	Output sustaining voltage	$I_{CEO}=100\mu\text{A}$		40		V	
$V_{CE(\text{sat})}$	Output saturation voltage	$V_I=8\text{V}, I_C=400\text{mA}$		1.15	2.4	V	
		$V_I=4\text{V}, I_C=200\text{mA}$		0.94	1.6		
$I_I$	Input current	$V_I=17\text{V}$		0.3	0.9	mA	
$V_F$	Clamp diode forward voltage	$I_F=400\text{mA}$			1.5	2.4	V
$V_R$	Clamp diode reverse voltage	$I_R=100\mu\text{A}$		40		V	
$h_{FE}$	DC forward current gain	$V_{CE}=4\text{V}, I_C=300\text{mA}, T_a=25^\circ\text{C}$		1000	8000	—	

\* : Typical values are at  $T_a=25^\circ\text{C}$ .**TYPICAL CHARACTERISTICS**

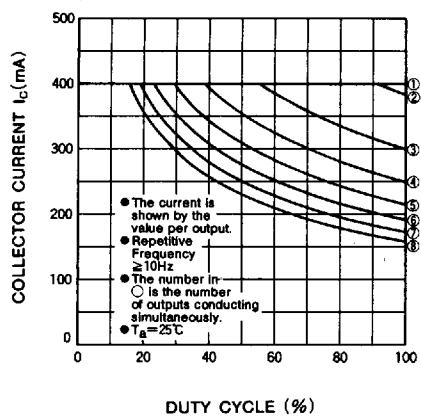
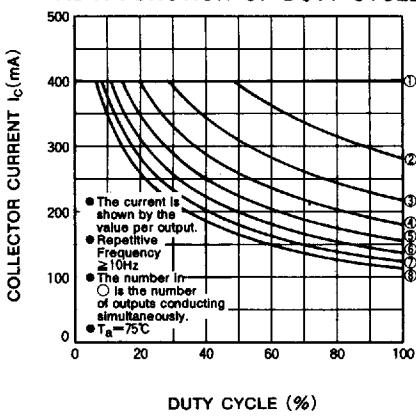
ALLOWABLE AVERAGE POWER DISSIPATION



OUTPUT CURRENT CHARACTERISTICS



MITSUBISHI (DGTL LOGIC)

**8-UNIT 400mA DARLINGTON TRANSISTOR ARRAY WITH CLAMP DIODE****ALLOWABLE COLLECTOR CURRENT AS A FUNCTION OF DUTY CYCLE****ALLOWABLE COLLECTOR CURRENT AS A FUNCTION OF DUTY CYCLE****DC CURRENT GAIN CHARACTERISTICS**